## BFL4001 <br> General-Purpose Switching Device Applications

## Features

- Low ON-resistance.
- High-speed switching.
- Avalanche resistance guarantee.
- 10V drive.


## Specifications

Absolute Maximum Ratings at $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Drain-to-Source Voltage | VDSS |  | 900 | V |
| Gate-to-Source Voltage | VGSS |  | $\pm 30$ | V |
| Drain Current (DC) | $l_{\text {l }}{ }^{*} 1$ | Limited only by maximum temperature $\mathrm{Tch}=150^{\circ} \mathrm{C}$ | 6.5 | A |
|  | IDpack*2 | $\mathrm{Tc}=25^{\circ} \mathrm{C}$ (SANYO's ideal heat dissipation condition)*3 | 4.1 | A |
| Drain Current (Pulse) | IDP | $P W \leq 10 \mu s$, duty cycle $\leq 1 \%$ | 13 | A |
| Allowable Power Dissipation | PD |  | 2.0 | W |
|  |  | Tc $=25^{\circ} \mathrm{C}$ (SANYO's ideal heat dissipation condition*)3 | 37 | W |
| Channel Temperature | Tch |  | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature | Tstg |  | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Avalanche Energy (Single Pulse)*4 | EAS |  | 237 | mJ |
| Avalanche Current *5 | IAV |  | 6.5 | A |

Note :*1 Shows chip capability
*2 Package limited
*3 SANYO's condition is radiation from backside.
The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.
*4 V ${ }_{\mathrm{DD}}=99 \mathrm{~V}$, $\mathrm{L}=10 \mathrm{mH}, \mathrm{I}_{\mathrm{AV}}=6.5 \mathrm{~A}$

* $\mathrm{L} \leq 10 \mathrm{mH}$, single pulse

Marking : FL4001
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Electrical Characteristics at $\mathrm{Ta}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Ratings |  |  | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | min | typ | max |  |
| Drain-to-Source Breakdown Voltage | $\mathrm{V}_{\text {(BR) }}$ DSS | $\mathrm{I}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ | 900 |  |  | V |
| Zero-Gate Voltage Drain Current | IDSS | $\mathrm{V}_{\mathrm{DS}}=720 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  |  | 1.0 | mA |
| Gate-to-Source Leakage Current | IGSS | $\mathrm{V}_{\mathrm{GS}}= \pm 30 \mathrm{~V}, \mathrm{~V}_{\text {DS }}=0 \mathrm{~V}$ |  |  | $\pm 100$ | nA |
| Cutoff Voltage | $\mathrm{V}_{\mathrm{GS}}(\mathrm{off})$ | $\mathrm{V}_{\mathrm{DS}}=10 \mathrm{~V}, \mathrm{I}=1 \mathrm{~mA}$ | 2.0 |  | 4.0 | V |
| Forward Transfer Admittance | \| yfs | | $\mathrm{V}_{\mathrm{DS}}=20 \mathrm{~V}, \mathrm{ID}=3.25 \mathrm{~A}$ | 1.8 | 3.6 |  | S |
| Static Drain-to-Source On-State Resistance | RDS(on) | $\mathrm{I}_{\mathrm{D}}=3.25 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}$ |  | 2.1 | 2.7 | $\Omega$ |
| Input Capacitance | Ciss | VDS $=30 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 850 |  | pF |
| Output Capacitance | Coss | V ${ }_{\text {dS }}=30 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 130 |  | pF |
| Reverse Transfer Capacitance | Crss | VDS $=30 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  | 43 |  | pF |
| Turn-ON Delay Time | $\mathrm{t}_{\mathrm{d}}(\mathrm{on})$ | See specified Test Circuit. |  | 19 |  | ns |
| Rise Time | $\mathrm{tr}_{r}$ | See specified Test Circuit. |  | 49 |  | ns |
| Turn-OFF Delay Time | $\mathrm{t}_{\mathrm{d}}$ (off) | See specified Test Circuit. |  | 156 |  | ns |
| Fall Time | tf | See specified Test Circuit. |  | 52 |  | ns |
| Total Gate Charge | Qg | $\mathrm{V}_{\mathrm{DS}}=200 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=6.5 \mathrm{~A}$ |  | 44 |  | nC |
| Gate-to-Source Charge | Qgs | $\mathrm{V}_{\mathrm{DS}}=200 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=6.5 \mathrm{~A}$ |  | 7.0 |  | nC |
| Gate-to-Drain "M iller" Charge | Qgd | $\mathrm{V}_{\mathrm{DS}}=200 \mathrm{~V}, \mathrm{~V}_{\mathrm{GS}}=10 \mathrm{~V}, \mathrm{I}_{\mathrm{D}}=6.5 \mathrm{~A}$ |  | 22 |  | nC |
| Diode Forward Voltage | VSD | $\mathrm{IS}=6.5 \mathrm{~A}, \mathrm{~V}_{\mathrm{GS}}=0 \mathrm{~V}$ |  | 0.85 | 1.2 | V |

## Package Dimensions

unit : mm (typ)
7509-002


Switching Time Test Circuit


Avalanche Resistance Test Circuit








Note on usage : Since the BFL4001 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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